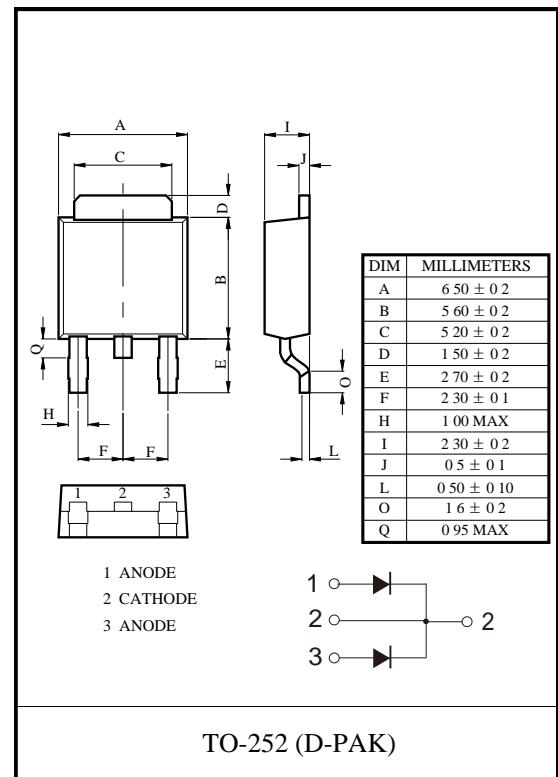


MBRD20200CT SCHOTTKY BARRIER RECTIFIER
FEATURES

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications


MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Unit
V_{RRM}	Peak repetitive reverse voltage	200	V
V_{RWM}	Working peak reverse voltage		
$V_{R(\text{RMS})}$	RMS reverse voltage	140	V
I_o	Average rectified output current	20	A
I_{FSM}	Non-repetitive peak forward surge current 8.3ms half sine wave	150	A
$R_{\theta JA}$	Thermal resistance from junction to ambient (note : Test with 2inch Al board)	100	°C/W
T_j	Junction temperature	150	°C
T_{stg}	Storage temperature	-55~+150	°C

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=1\text{ mA}$	200			V
Reverse current	I_R	$V_R=200\text{ V}$			100	μA
Forward voltage	$V_{F(1)}$	$I_F=10\text{ A}$ $T_j=25^\circ\text{C}$			0.92	V
	$V_{F(2)}^*$	$I_F=10\text{ A}$ $T_j=125^\circ\text{C}$			0.80	V
		$I_F=20\text{ A}$			1.2	V

*Pulse test

Typical Characteristics

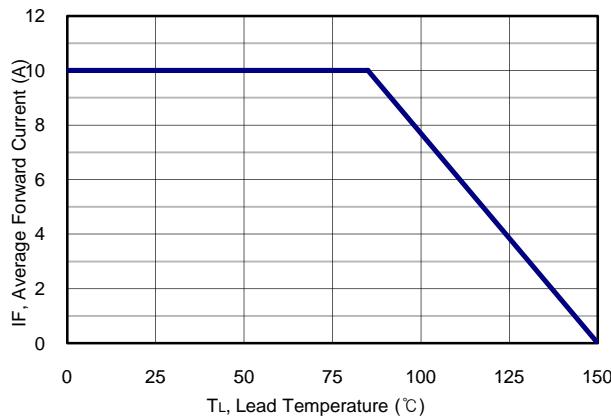


Figure 1: Current Derating Curves (Per Leg)

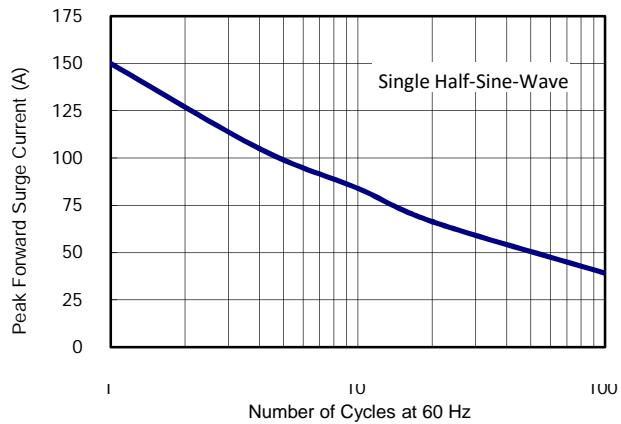


Figure 2: Peak Forward Surge Current (Per Leg)

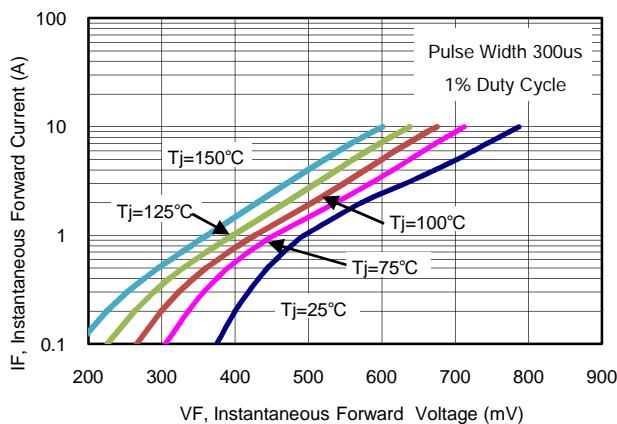


Figure 3: Typical Forward Characteristics
(MBRD20100CT) (Per Leg)

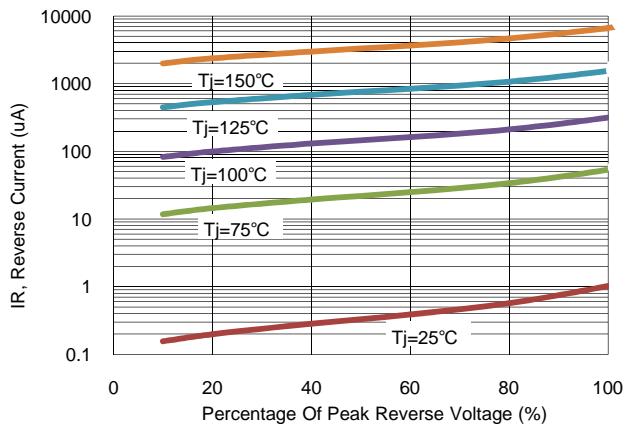


Figure 4: Typical Reverse Characteristics
(MBRD20100CT) (Per Leg)